

TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC74VCX86FT, TC74VCX86FK

Low-Voltage Quad 2-Input Exclusive OR Gate with 3.6-V Tolerant Inputs and Outputs

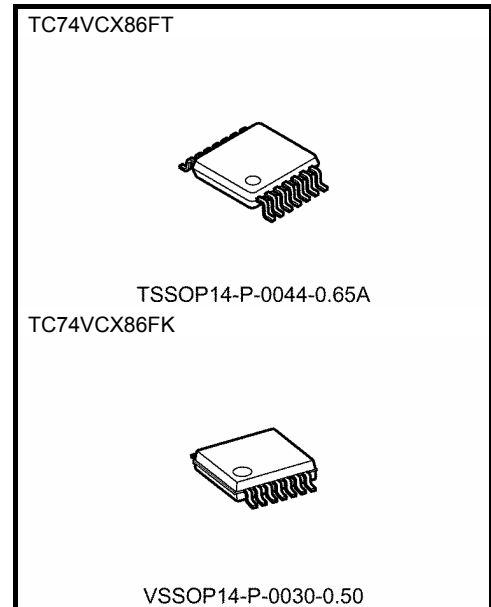
The TC74VCX86FT/FK is a high-performance CMOS exclusive OR gate which is guaranteed to operate from 1.2-V to 3.6-V. Designed for use in 1.5V, 1.8V, 2.5V or 3.3V systems, it achieves high-speed operation while maintaining the CMOS low power dissipation.

It is also designed with overvoltage tolerant inputs and outputs up to 3.6 V.

All inputs are equipped with protection circuits against static discharge.

Features

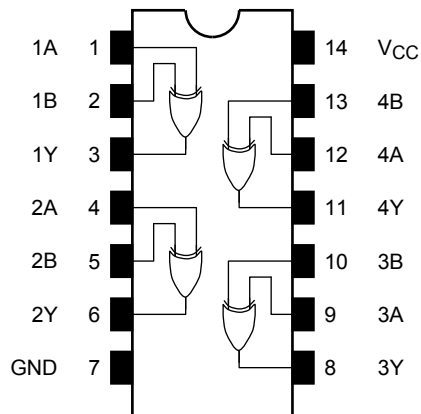
- Low-voltage operation: $V_{CC} = 1.2 \sim 3.6 \text{ V}$
- High-speed operation : $t_{pd} = 3.0 \text{ ns (max)}$ ($V_{CC} = 3.0 \sim 3.6 \text{ V}$)
 : $t_{pd} = 3.9 \text{ ns (max)}$ ($V_{CC} = 2.3 \sim 2.7 \text{ V}$)
 : $t_{pd} = 7.8 \text{ ns (max)}$ ($V_{CC} = 1.65 \sim 1.95 \text{ V}$)
 : $t_{pd} = 15.6 \text{ ns (max)}$ ($V_{CC} = 1.4 \sim 1.6 \text{ V}$)
 : $t_{pd} = 39.0 \text{ ns (max)}$ ($V_{CC} = 1.2 \text{ V}$)
- Output current: $I_{OH}/I_{OL} = \pm 24 \text{ mA (min)}$ ($V_{CC} = 3.0 \text{ V}$)
 : $I_{OH}/I_{OL} = \pm 18 \text{ mA (min)}$ ($V_{CC} = 2.3 \text{ V}$)
 : $I_{OH}/I_{OL} = \pm 6 \text{ mA (min)}$ ($V_{CC} = 1.65 \text{ V}$)
 : $I_{OH}/I_{OL} = \pm 2 \text{ mA (min)}$ ($V_{CC} = 1.4 \text{ V}$)
- Latch-up performance: -300 mA
- ESD performance: Machine model $\geq \pm 200 \text{ V}$
 Human body model $\geq \pm 2000 \text{ V}$
- Package: TSSOP and VSSOP (US)
- Power-down protection provided on all inputs and outputs



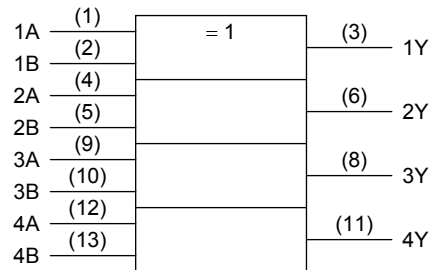
Weight

TSSOP14-P-0044-0.65A	: 0.06g (typ.)
VSSOP14-P-0030-0.50	: 0.02 g (typ.)

Pin Assignment (top view)



IEC Logic Symbol



Truth Table

A	B	Y
L	L	L
L	H	H
H	L	H
H	H	L

Absolute Maximum Ratings (Note 1)

Characteristics	Symbol	Rating	Unit
Power supply voltage	V_{CC}	-0.5~4.6	V
DC input voltage	V_{IN}	-0.5~4.6	V
DC output voltage	V_{OUT}	-0.5~4.6 (Note 2)	V
		-0.5~ $V_{CC} + 0.5$ (Note 3)	
Input diode current	I_{IK}	-50	mA
Output diode current	I_{OK}	±50 (Note 4)	mA
DC output current	I_{OUT}	±50	mA
Power dissipation	P_D	180	mW
DC V_{CC} /ground current	I_{CC}/I_{GND}	±100	mA
Storage temperature	T_{stg}	-65~150	°C

Note 1: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 2: $V_{CC} = 0$ V

Note 3: High or low state. I_{OUT} absolute maximum rating must be observed.

Note 4: $V_{OUT} < GND$, $V_{OUT} > V_{CC}$

Operating Ranges (Note 1)

Characteristics	Symbol	Rating	Unit
Power supply voltage	V_{CC}	1.2~3.6	V
Input voltage	V_{IN}	-0.3~3.6	V
Output voltage	V_{OUT}	0~3.6 (Note 2)	V
		0~ V_{CC} (Note 3)	
Output current	I_{OH}/I_{OL}	± 24 (Note 4)	mA
		± 18 (Note 5)	
		± 6 (Note 6)	
		± 2 (Note 7)	
Operating temperature	T_{opr}	-40~85	°C
Input rise and fall time	dt/dv	0~10 (Note 8)	ns/V

Note 1: The operating ranges must be maintained to ensure the normal operation of the device.
Unused inputs must be tied to either V_{CC} or GND.

Note 2: $V_{CC} = 0$ V

Note 3: High or low state

Note 4: $V_{CC} = 3.0\sim 3.6$ V

Note 5: $V_{CC} = 2.3\sim 2.7$ V

Note 6: $V_{CC} = 1.65\sim 1.95$ V

Note 7: $V_{CC} = 1.4\sim 1.6$ V

Note 8: $V_{IN} = 0.8\sim 2.0$ V, $V_{CC} = 3.0$ V

Electrical Characteristics

DC Characteristics ($T_a = -40$ to 85°C , $2.7\text{ V} < V_{CC} \leq 3.6\text{ V}$)

Characteristics		Symbol	Test Condition			Min	Max	Unit
					V _{CC} (V)			
Input voltage	“H” level	V _{IH}	—		2.7~3.6	2.0	—	V
	“L” level	V _{IL}	—		2.7~3.6	—	0.8	
Output voltage	“H” level	V _{OH}	V _{IN} = V _{IH} or V _{IL}	I _{OH} = -100 μA	2.7~3.6	V _{CC} - 0.2	—	V
				I _{OH} = -12 mA	2.7	2.2	—	
				I _{OH} = -18 mA	3.0	2.4	—	
				I _{OH} = -24 mA	3.0	2.2	—	
	“L” level	V _{OL}	V _{IN} = V _{IH} or V _{IL}	I _{OL} = 100 μA	2.7~3.6	—	0.2	
				I _{OL} = 12 mA	2.7	—	0.4	
				I _{OL} = 18 mA	3.0	—	0.4	
				I _{OL} = 24 mA	3.0	—	0.55	
Input leakage current		I _{IN}	V _{IN} = 0 to 3.6 V		2.7~3.6	—	±5.0	μA
Power off leakage current		I _{OFF}	V _{IN} , V _{OUT} = 0 to 3.6 V		0	—	10.0	μA
Quiescent supply current		I _{CC}	V _{IN} = V _{CC} or GND		2.7~3.6	—	20.0	μA
			V _{CC} ≤ V _{IN} ≤ 3.6 V		2.7~3.6	—	±20.0	
Increase in I _{CC} per input		ΔI _{CC}	V _{IH} = V _{CC} - 0.6 V		2.7~3.6	—	750	

DC Characteristics ($T_a = -40$ to 85°C , $2.3\text{ V} \leq V_{CC} \leq 2.7\text{ V}$)

Characteristics		Symbol	Test Condition			Min	Max	Unit	
			V _{CC} (V)						
Input voltage	H-level	V _{IH}	—			2.3~2.7	1.6	—	V
	L-level	V _{IL}	—			2.3~2.7	—	0.7	
Output voltage	H-level	V _{OH}	V _{IN} = V _{IH} or V _{IL}	I _{OH} = −100 μA	2.3~2.7	V _{CC} − 0.2	—	V	
				I _{OH} = −6 mA	2.3	2.0	—		
				I _{OH} = −12 mA	2.3	1.8	—		
				I _{OH} = −18 mA	2.3	1.7	—		
	L-level	V _{OL}	V _{IN} = V _{IH} or V _{IL}	I _{OL} = 100 μA	2.3~2.7	—	0.2		
				I _{OL} = 12 mA	2.3	—	0.4		
				I _{OL} = 18 mA	2.3	—	0.6		
Input leakage current		I _{IN}	V _{IN} = 0 to 3.6 V			2.3~2.7	—	±5.0	μA
Power-off leakage current		I _{OFF}	V _{IN} , V _{OUT} = 0 to 3.6 V			0	—	10.0	μA
Quiescent supply current		I _{CC}	V _{IN} = V _{CC} or GND			2.3~2.7	—	20.0	μA
			V _{CC} ≤ V _{IN} ≤ 3.6 V			2.3~2.7	—	±20.0	

DC Characteristics ($T_a = -40$ to 85°C , $1.65\text{ V} \leq V_{CC} < 2.3\text{ V}$)

Characteristics		Symbol	Test Condition		V _{CC} (V)	Min	Max	Unit
Input voltage	H-level	V _{IH}	—		1.65~2.3	0.65 × V _{CC}	—	V
	L-level	V _{IL}	—		1.65~2.3	—	0.2 × V _{CC}	
Output voltage	H-level	V _{OH}	V _{IN} = V _{IH} or V _{IL}	I _{OH} = −100 μA	1.65~2.3	V _{CC} − 0.2	—	V
				I _{OH} = −6 mA	1.65	1.25	—	
	L-level	V _{OL}	V _{IN} = V _{IH} or V _{IL}	I _{OL} = 100 μA	1.65~2.3	—	0.2	
				I _{OL} = 6 mA	1.65	—	0.3	
Input leakage current		I _{IN}	V _{IN} = 0 to 3.6 V		1.65~2.3	—	±5.0	μA
Power-off leakage current		I _{OFF}	V _{IN} , V _{OUT} = 0 to 3.6 V		0	—	10.0	μA
Quiescent supply current		I _{CC}	V _{IN} = V _{CC} or GND		1.65~2.3	—	20.0	μA
			V _{CC} ≤ V _{IN} ≤ 3.6 V		1.65~2.3	—	±20.0	

DC Characteristics (Ta = -40 to 85°C, 1.4 V ≤ V_{CC} < 1.65 V)

Characteristics		Symbol	Test Condition			Min	Max	Unit	
			V _{CC} (V)						
Input voltage	H-level	V _{IH}	—			1.4~1.65	0.65 × V _{CC}	—	V
	L-level	V _{IL}	—			1.4~1.65	—	0.2 × V _{CC}	
Output voltage	H-level	V _{OH}	V _{IN} = V _{IH} or V _{IL}	I _{OH} = -100 μA	1.4~1.65	V _{CC} - 0.2	—	V	
				I _{OH} = -2 mA	1.4	1.05	—		
	L-level	V _{OL}	V _{IN} = V _{IH} or V _{IL}	I _{OL} = 100 μA	1.4~1.65	—	0.05		
				I _{OL} = 2 mA	1.4	—	0.35		
Input leakage current		I _{IN}	V _{IN} = 0 to 3.6 V			1.4~1.65	—	±5.0	μA
Power-off leakage current		I _{OFF}	V _{IN} , V _{OUT} = 0 to 3.6 V			0	—	10.0	μA
Quiescent supply current		I _{CC}	V _{IN} = V _{CC} or GND			1.4~1.65	—	20.0	μA
			V _{CC} ≤ V _{IN} ≤ 3.6 V			1.4~1.65	—	±20.0	

DC Characteristics (Ta = -40 to 85°C, 1.2 V ≤ V_{CC} < 1.4 V)

Characteristics		Symbol	Test Condition		V _{CC} (V)	Min	Max	Unit
Input voltage	H-level	V _{IH}	—		1.2~1.4	0.8 × V _{CC}	—	V
	L-level	V _{IL}	—		1.2~1.4	—	0.05 × V _{CC}	
Output voltage	H-level	V _{OH}	V _{IN} = V _{IH} or V _{IL}	I _{OH} = -100 μA	1.2	V _{CC} - 0.1	—	V
	L-level	V _{OL}	V _{IN} = V _{IH} or V _{IL}	I _{OL} = 100 μA	1.2	—	0.05	
Input leakage current		I _{IN}	V _{IN} = 0 to 3.6 V		1.2	—	±5.0	μA
Power-off leakage current		I _{OFF}	V _{IN} , V _{OUT} = 0 to 3.6 V		0	—	10.0	μA
Quiescent supply current		I _{CC}	V _{IN} = V _{CC} or GND		1.2	—	20.0	μA
			V _{CC} ≤ V _{IN} ≤ 3.6 V		1.2	—	±20.0	

AC Characteristics (Ta = -40 to 85°C, input: tr = tf = 2.0 ns) (Note)

Characteristics	Symbol	Test Condition		Min	Max	Unit
Propagation delay time	tpLH tpHL	Figure 1, Figure 2	CL = 15 pF, RL = 2 kΩ	1.2	1.5	39.0
				1.5 ± 0.1	1.0	15.6
			CL = 30 pF, RL = 500 Ω	1.8 ± 0.15	1.5	7.8
				2.5 ± 0.2	0.8	3.9
				3.3 ± 0.3	0.6	3.0

Note: For CL = 50 pF, add approximately 300 ps to the AC maximum specification.

Dynamic Switching Characteristics (Ta = 25°C, input: tr = tf = 2.0 ns, CL = 30 pF)

Characteristics	Symbol	Test Condition		Typ.	Unit
Quiet output maximum dynamic VOL	VOLP	VIH = 1.8 V, VIL = 0 V	(Note)	1.8	0.25
		VIH = 2.5 V, VIL = 0 V	(Note)	2.5	0.6
		VIH = 3.3 V, VIL = 0 V	(Note)	3.3	0.8
Quiet output minimum dynamic VOL	VOLV	VIH = 1.8 V, VIL = 0 V	(Note)	1.8	-0.25
		VIH = 2.5 V, VIL = 0 V	(Note)	2.5	-0.6
		VIH = 3.3 V, VIL = 0 V	(Note)	3.3	-0.8
Quiet output minimum dynamic VOH	VOHV	VIH = 1.8 V, VIL = 0 V	(Note)	1.8	1.5
		VIH = 2.5 V, VIL = 0 V	(Note)	2.5	1.9
		VIH = 3.3 V, VIL = 0 V	(Note)	3.3	2.2

Note: Parameter guaranteed by design.

Capacitive Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition		Typ.	Unit
Input capacitance	CIN	—	1.8, 2.5, 3.3	6	pF
Power dissipation capacitance	CPD	fIN = 10 MHz	(Note)	1.8, 2.5, 3.3	20

Note: CPD is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

$$I_{CC(opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/4 \text{ (per gate)}$$

AC Test Circuit

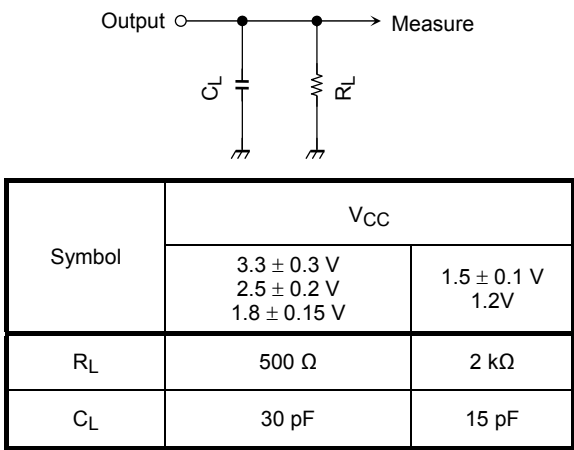


Figure 1

AC Waveform

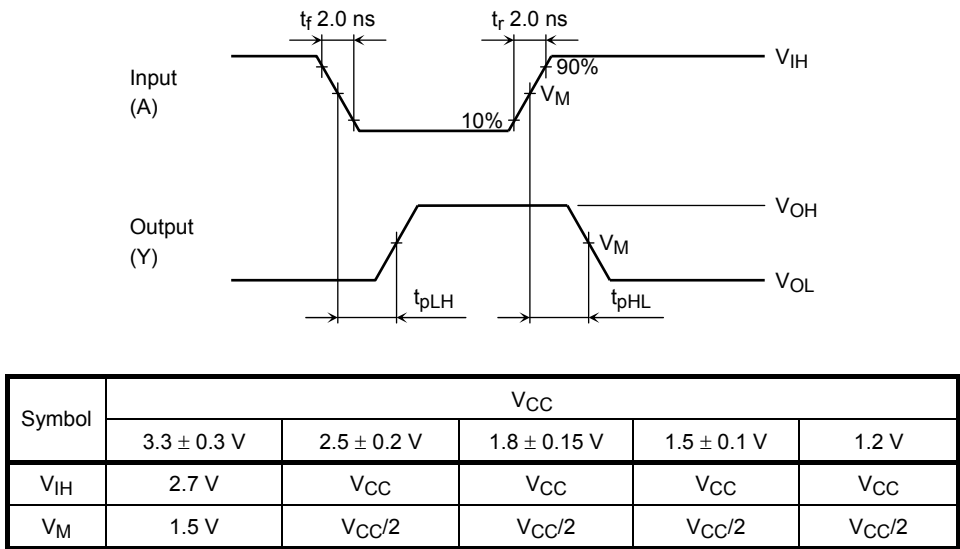
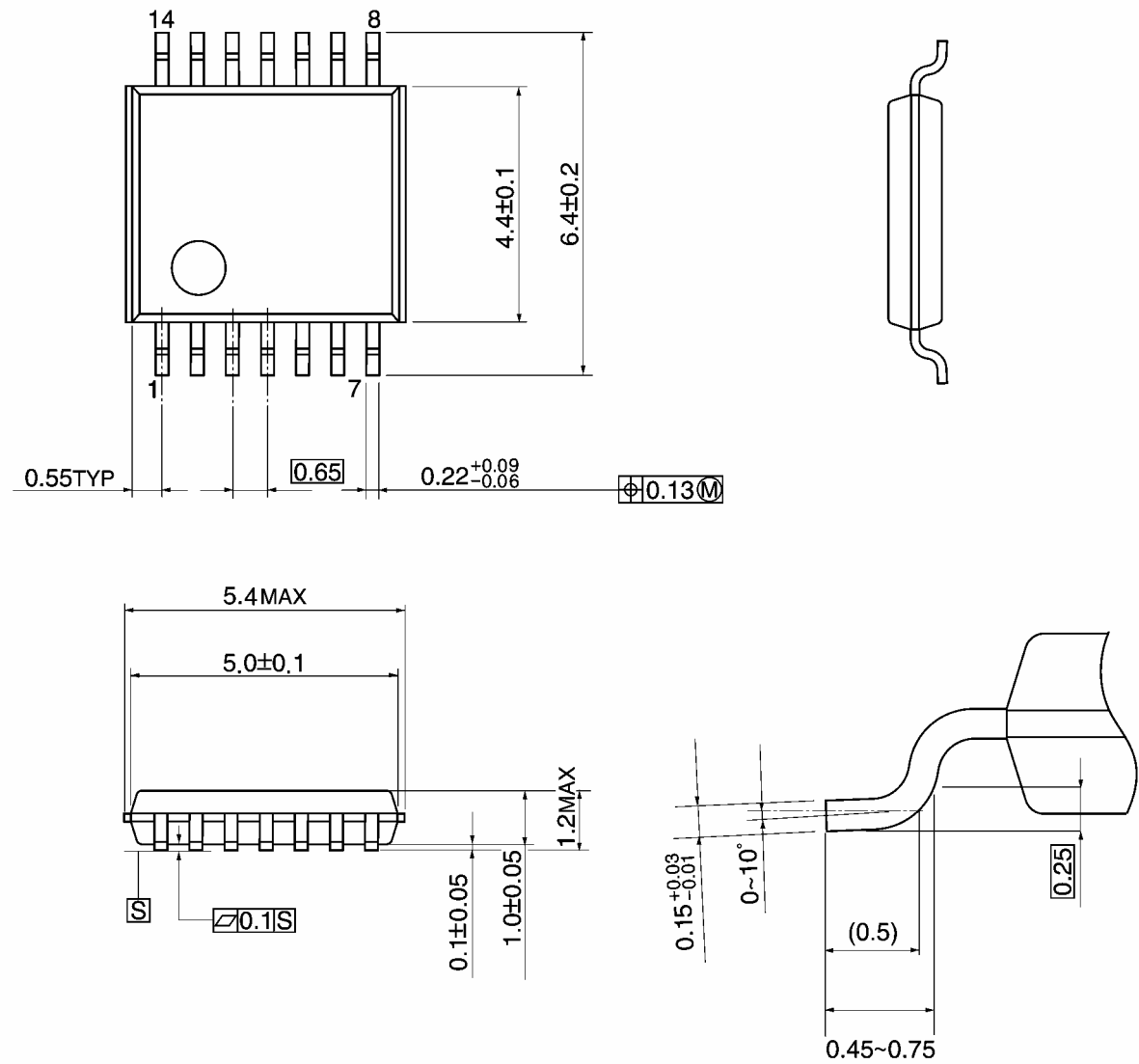


Figure 2 t_{pLH} , t_{pHL}

Package Dimensions

TSSOP14-P-0044-0.65A

Unit: mm

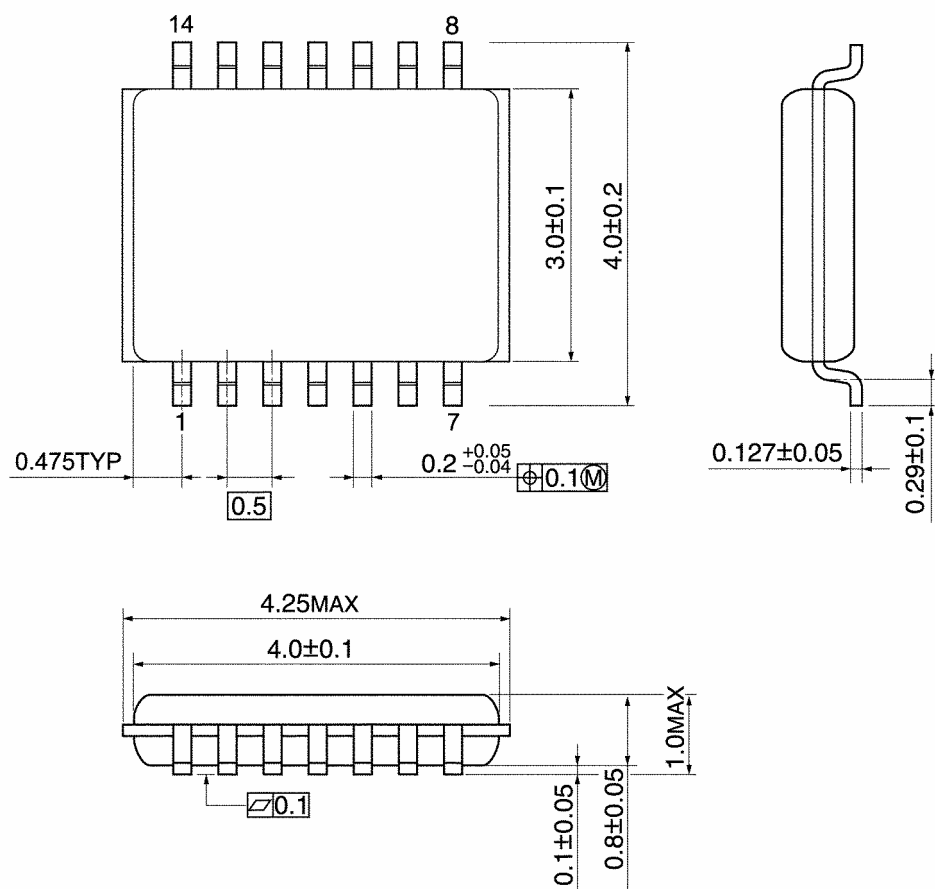


Weight: 0.06g (typ.)

Package Dimensions

VSSOP14-P-0030-0.50

Unit: mm



Weight: 0.02 g (typ.)

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20070701-EN GENERAL

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